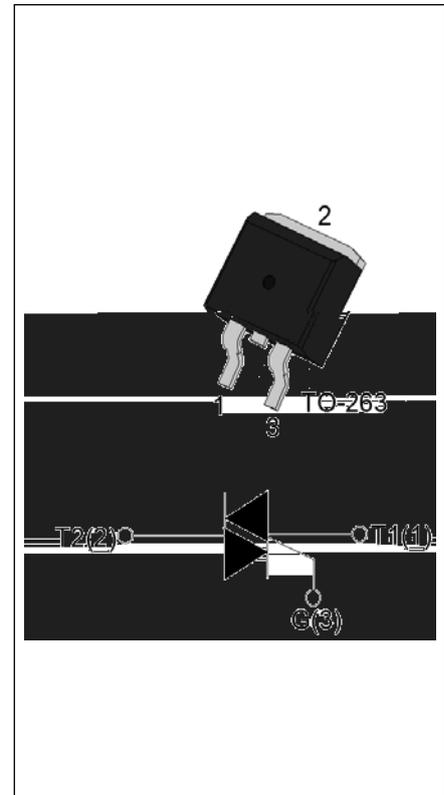


The T0810H-6E triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Compared to traditional triacs, T0810H-6E provides a very high switching capability up to junction temperatures of 150°C. It can be driven directly through the MCU I/O port. Package TO-263 is RoHS compliant.



Symbol	Value	Unit
$I_{T(RMS)}$	8	A
$V_{DRM}/V_{RRM}$	600	V
$I_{GT} / /$	10/10/10	mA

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-150	
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	600	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	600	V
RMS on-state current ( $T_c = 133^\circ\text{C}$ )	$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	80	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		88	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	32	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 I_{GT}$ , $f=100\text{Hz}$ , $T_j=150^\circ\text{C}$ )	$di/dt$	50	$\text{A}/\mu\text{s}$
Peak gate current ( $t_p=20\mu\text{s}$ , $T_j=150^\circ\text{C}$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=150^\circ\text{C}$ )	$P_{G(AV)}$	1	W

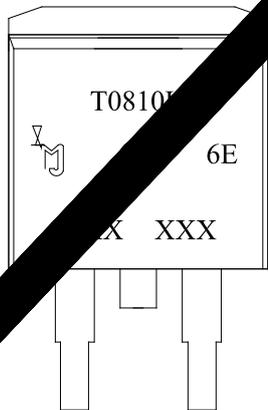
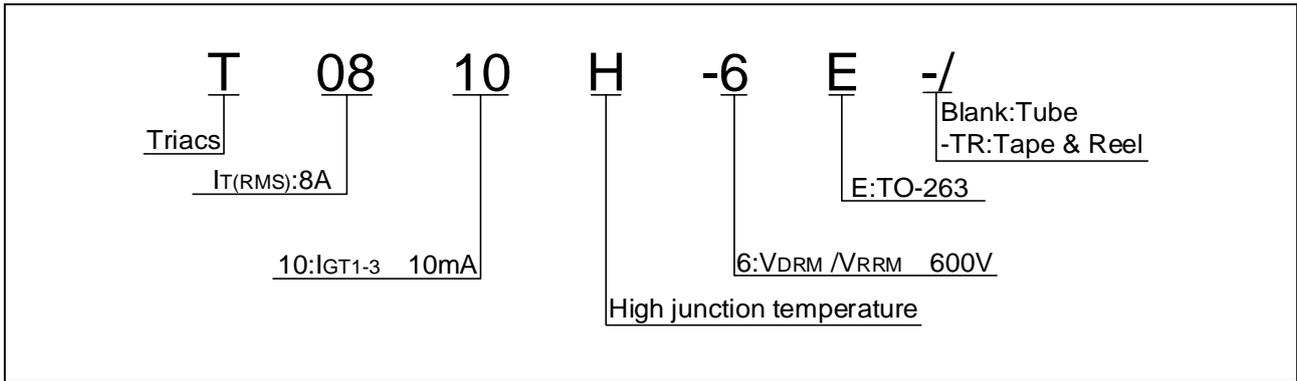
Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25$ ; non-repetitive, off-state; FIG.8)	$V_{pp}$	2.5	kV

(T<sub>j</sub>=25 unless otherwise specified)

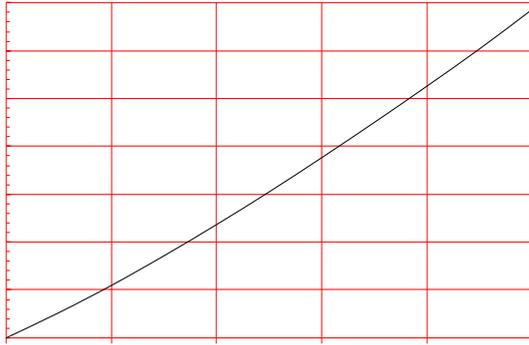
Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D=12V R_L=33$	- -	MAX.	10	mA
$V_{GT}$		- -	MAX.	1	V
$V_{GD}$	$V_D=V_{DRM} T_j=150$ $R_L=3.3K$	- -	MIN.	0.2	V
$I_L$	$I_G=1.2I_{GT}$	-	MAX.	25	mA
				40	
$I_H$	$I_T=100mA$		MAX.	25	mA
dV/dt	$V_D=400V$ Gate Open $T_j=150$		MIN.	200	V/μs
(dI/dt) <sub>c</sub>	(dV/dt) <sub>c</sub> =20V/μs, $T_j=150$		MIN.	1.8	A/ms
$t_{on}$	$I_G=20mA I_A=200mA I_R=20mA$ $T_j=25$		TYP.	2.5	μs
$t_{off}$				25	

Symbol	Parameter		Value(MAX.)	Unit
$V_{TM}$	$I_{TM}=11A t_p=380\mu s$	$T_j=25$	1.4	V
$V_{TO}$	Threshold voltage	$T_j=150$	0.79	V
$R_D$	Dynamic resistance	$T_j=150$	51	m
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25$	5	μA
$I_{RRM}$		$T_j=150$	1	mA

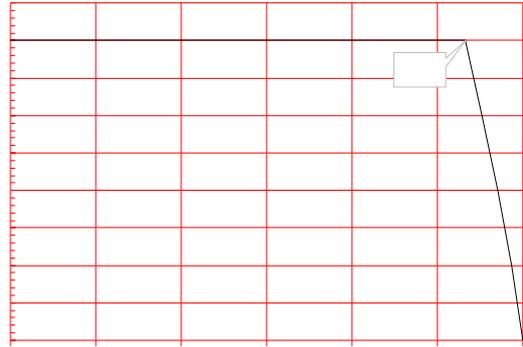
Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	1.6	W
$R_{th(j-a)}$	junction to ambient (AC, in free air, S=2cm <sup>2</sup> )	45	W



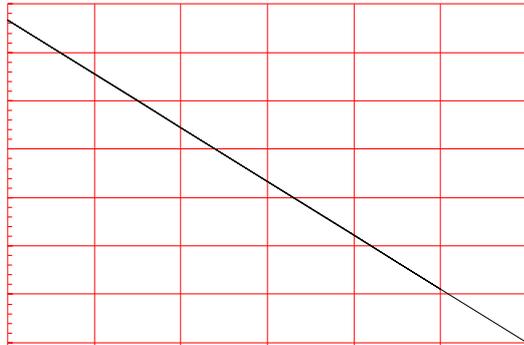
**FIG.1** Maximum power dissipation versus RMS on-state current



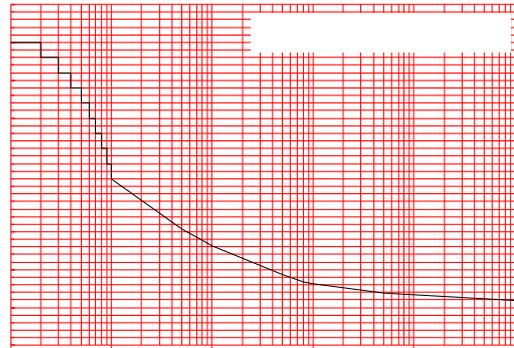
**FIG.2:** RMS on-state current versus case temperature



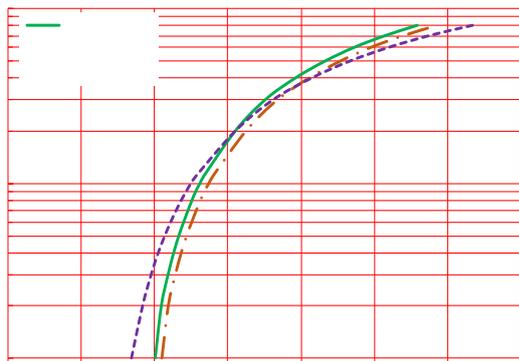
**FIG.3:** RMS on-state current versus ambient temperature (printed circuit board FR4,copper thickness:35 $\mu$ m)(full cycle)



**FIG.4:** Surge peak on-state current versus number of cycles



**FIG.5:** On-state characteristics



**FIG.6:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20$ ms, and corresponding value of  $I^2t$  ( $dI/dt < 50$ A/ $\mu$ s)

**FIG.7:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

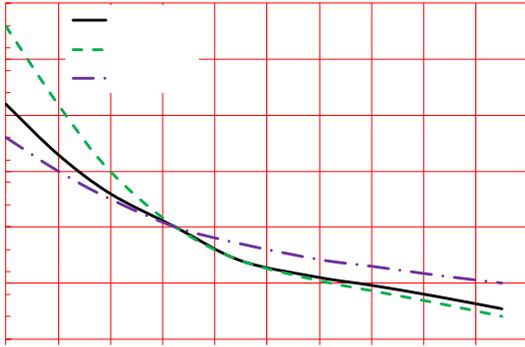
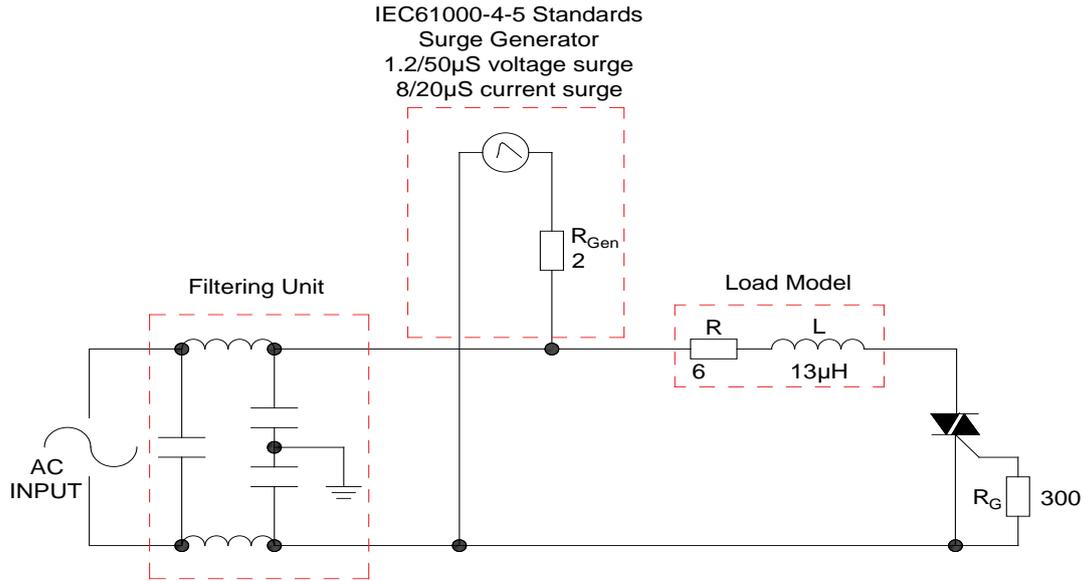
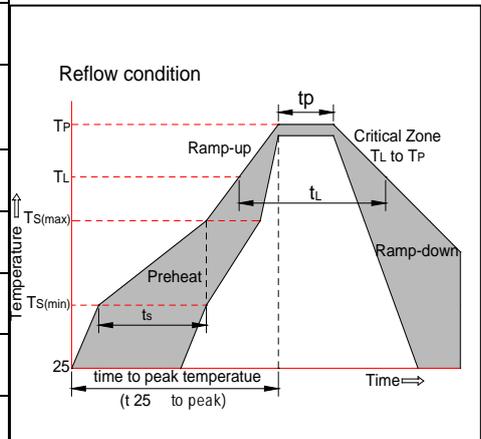


FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



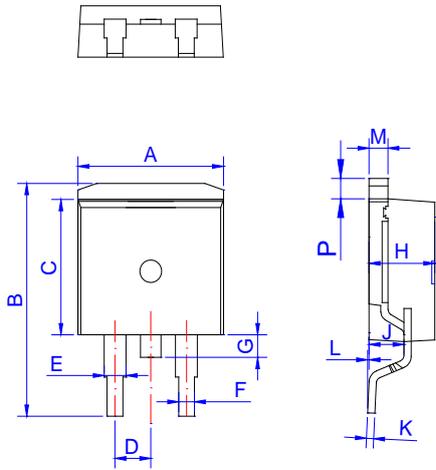
Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150
	-Temperature Max( $T_{s(max)}$ )	+200
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		3 /sec. Max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		3 /sec. Max
Reflow	-Temperature( $T_L$ )(Liquidus)	+217
	-Temperature( $t_L$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0/-5)
Time within 5 of actual Peak Temp ( $t_p$ )		20-40secs.
Ramp-down Rate		6 /sec. Max
Time 25 to Peak Temp ( $T_p$ )		8 min. Max
Do not exceed		+260



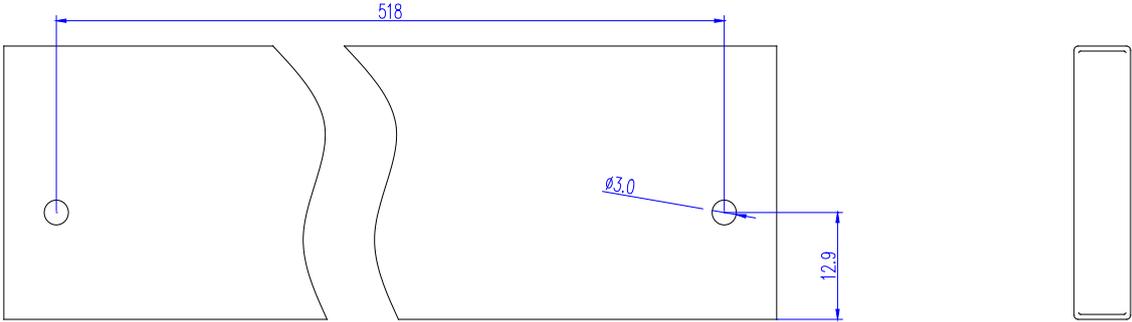
Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
T0810H-6E	600	10	TO-263	50	Tube
T0810H-6E-TR				800	Tape & Reel

**Document Revision History**

Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.37		0.378
D	2.40		2.70	0.094		0.106
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033
G	1.00		1.50	0.039		0.059
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.25		1.35	0.049		0.053
P	1.20		1.50	0.047		0.059



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